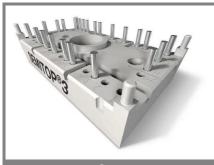
SK 80 DTA



SEMITOP® 3

V_{RSM} V_{RRM}, V_{DRM} I_D = 81 A V V (T_s = 80 °C) 900 800 SK 80 DTA 08 1300 1200 SK 80 DTA 12 1700 1600 SK 80 DTA 16

3-phase bridge rectifier+ series thyristor

SK 80 DTA

Preliminary Data

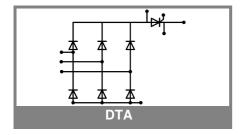
Features

- · Compact design
- · One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passivated thyristor chips
- Reverse voltage up to 1600 V
- High surge currents

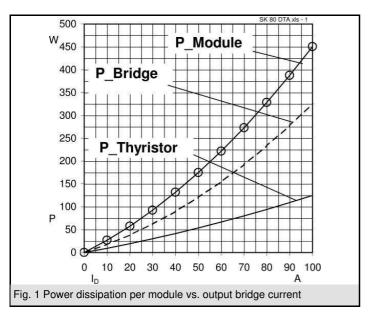
Typical Applications*

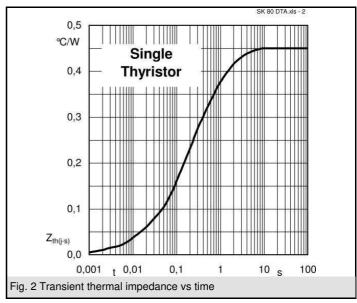
- Soft starters
- Light control
- Temperature control

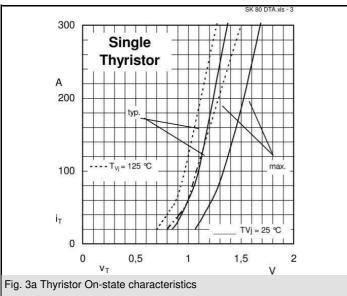
Characteristics T _s = 1			25°C unless otherwise specified	
Symbol	Conditions		Values	Units
I _D	T _S = 80°C; Ind. load		81	Α
I_{TAV}	sin. 180°; T _s = 25 (80) °C per thyristor		113 (65)	Α
I _{FAV}	sin. 180°; T _s = 25 (80) °C per diode		65 (45)	Α
I _{TSM} /I _{FSM}	T _{vj} = 25 (125) °C; 10 ms		2000 (1800)	Α
l²t	T _{vj} = 25 (125) °C; 8,3 10 ms		20000 (16200)	A²s
T _{stg}			-40,+125	°C
T _{solder}	terminals, 10 s		260	°C
Thyristor	•			
(dv/dt) _{cr}	T _{vj} = 125 °C		1000	V/µs
(di/dt) _{cr}	$T_{vj} = 125 ^{\circ}\text{C}; f = f = \text{Hz}$		50	A/µs
t_q	T_{vj} = 125 °C; typ.		120	μs
I _H	T_{vj} = 25 °C; typ. / max.		100 / 200	mA
IL	$T_{vj} = 25 ^{\circ}\text{C}; R_{G} = 33 \Omega; \text{typ. / max.}$		200 / 500	mA
V _T	$T_{vj} = 25 \text{ °C}; (I_T = 300 \text{ A}); \text{ max}.$		1,85	V
$V_{T(TO)}$	T _{vi} = 125 °C		max. 0,9	V
r _T	T _{vj} = 125 °C		max. 3,5	mΩ
$I_{DD}; I_{RD}$	T_{vj} = 125 °C; $V_{DD} = V_{DRM}$; $V_{RD} = V_{RRM}$		max. 20	mA
$R_{th(j-s)}$	Cont. per thyristor		0,45	K/W
T_{vi}			- 40 + 125	°C
V_{GT}	$T_{vj} = 25 ^{\circ}\text{C}; \text{d.c.}$		2	V
I_{GT}	$T_{vj} = 25 ^{\circ}\text{C}; \text{d.c.}$		100	mA
V_{GD}	T_{vj}^{j} = 125 °C; d.c.		0,25	V
I_{GD}	T _{vj} = 125 °C; d.c.		5	mA
Diode				
V_{F}	T_{vj} = 25 °C; (I_F = 75 A); max.		1,45	V
$V_{(TO)}$	T _{vj} = 125 °C		0,8	V
r_T	T _{vj} = 125 °C		4,5	mΩ
I_{RD}	T_{vj} = 125 °C; V_{RD} = V_{RRM}		2	mA
$R_{th(j-s)}$	per diode		1	K/W
T_{vj}			-40+150	°C
Mechanic	cal data			
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min		3000 (2500)	V
M_1	mounting torque		2,5	Nm
w			30	g
Case	SEMITOP® 3		T 45	
	T. Control of the con			

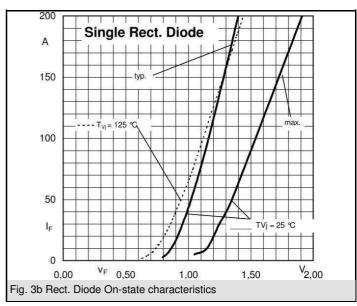


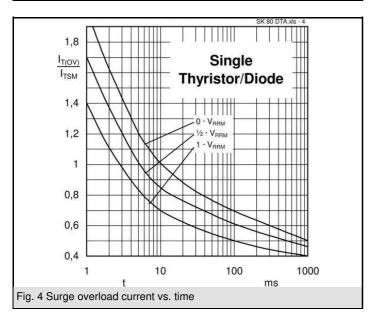
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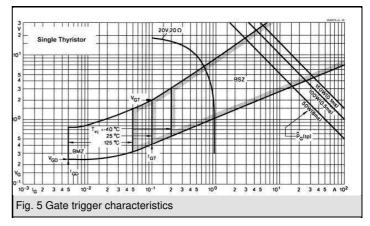


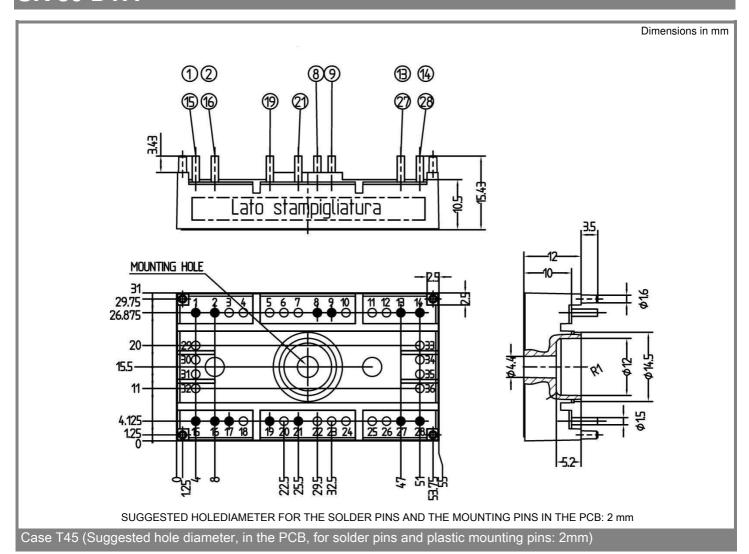


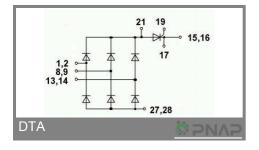












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.